INTEGRATED CIRCUITS



Product specification IC24 Data Handbook 1996 Aug 28



Philips Semiconductors

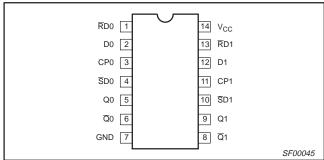
74LVT74

3.3V Dual D-type flip-flop

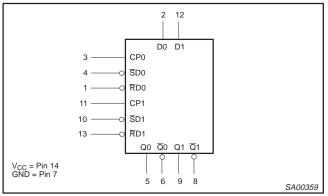
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay CPn to Qn	C _L = 50pF; V _{CC} = 3.3V	3.1 3.6	ns
C _{IN}	Input capacitance	V _I = 0V or 3.0V	3	pF
Icc	Total supply current	V _{CC} = 3.6V	0.5	mA

PIN CONFIGURATION



LOGIC SYMBOL



ORDERING INFORMATION

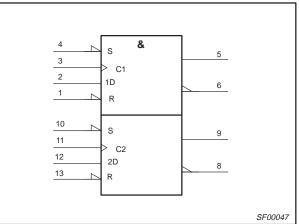
DESCRIPTION

The 74LVT74 is a dual positive edge-triggered D-type flip-flop featuring individual data, clock, set, and reset inputs; also true and complementary outputs. Set (SD) and reset (RD) are asynchronous active low inputs and operate independently of the clock input. When set and reset are inactive (high), data at the D input is transferred to the Q and \overline{Q} outputs on the low-to-high transition of the clock. Data must be stable just one setup time prior to the low-to-high transition of the clock for predictable operation. Clock triggering occurs at a voltage level and is not directly related to the transition time of the positive-going pulse. Following the hold time interval, data at the D input may be changed without affecting the levels of the output.

PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
2, 12	D0, D1	Data inputs
3, 11	CP0, CP1	Clock inputs (active rising edge)
4, 10	$\overline{S}D0, \overline{S}D1$	Set inputs (active LOW)
1, 13	RD0, RD1	Reset inputs (active LOW)
5, 6, 8, 9	Qn, Qn	Data outputs

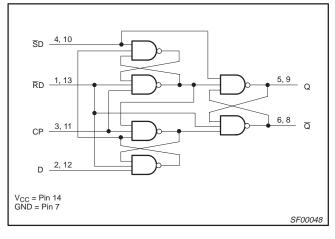
LOGIC SYMBOL (IEEE/IEC)



PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic SO	–40°C to +85°C	74LVT74 D	74LVT74 D	SOT108-1
14-Pin Plastic SSOP	–40°C to +85°C	74LVT74 DB	74LVT74 DB	SOT337-1
14-Pin Plastic TSSOP	-40°C to +85°C	74LVT74 PW	74LVT74PW DH	SOT402-1

74LVT74

LOGIC DIAGRAM



FUNCTION TABLE

INPUTS			OUTE	PUTS	OPERATING	
SD	RD	СР	D	Q	Q	MODE
L	Н	Х	Х	Н	L	Asynchronous set
Н	L	Х	Х	L	Н	Asynchronous reset
L	L	Х	Х	Н	Н	Undetermined*
Н	Н	\uparrow	h	Н	L	Load "1"
Н	Н	\uparrow	Ι	L	Н	Load "0"
Н	Н		Х	NC	NC	Hold

NOTES:

L

H = High voltage level

High voltage level one setup time prior to low-to-high h = clock transition

Low voltage level =

Low voltage level one setup time prior to low-to-high = clock transition

NC= No change from the previous setup

Don't care X ↑ ↓ =

- = Low-to-high clock transition
- Not low-to-high clock transition
 This setup is unstable and will change when either set or reset return to the high level.

SYMBOL	PARAMETER	PARAMETER CONDITIONS		UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V _I < 0	-50	mA
VI	DC input voltage ³		-0.5 to +7.0	V
I _{OK}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
1	DC output current	Output in High state	-32	mA
IOUT		Output in Low state	64	
T _{stg}	Storage temperature range		-65 to 150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT	
	FARAMETER	MIN		
V _{CC}	DC supply voltage	2.7	3.6	V
VI	Input voltage		5.5	V
V _{IH}	High-level input voltage			V
V _{IL}	Low-level Input voltage		0.8	V
I _{OH}	High-level output current		-20	mA
I _{OL}	Low-level output current		32	mA
$\Delta t/\Delta v$	Input transition rise or fall rate; Outputs enabled		10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

ABSOLUTE MAXIMUM RATINGS^{1, 2}

74LVT74

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions Voltages are referenced to \vec{GND} (ground = 0V)

			1	IMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = -	+85°C	UNIT		
			MIN	TYP ¹	MAX	1	
V _{IK}	Input clamp voltage	$V_{CC} = 2.7V; I_{IK} = -18mA$			-1.2	V	
		$V_{CC} = 2.7$ to 3.6V; $I_{OH} = -100\mu A$	V _{CC} -0.2				
V _{OH}	High-level output voltage	$V_{CC} = 2.7V; I_{OH} = -6mA$	2.4			V	
		$V_{CC} = 3.0V; I_{OH} = -20mA$	2.0]	
	Low-level output voltage	$V_{CC} = 2.7V; I_{OL} = 100\mu A$			0.2	V	
V _{OL}		$V_{CC} = 2.7V; I_{OL} = 24mA$			0.5		
		$V_{CC} = 3.0V; I_{OL} = 32mA$			0.5		
łı	Input leakage current	$V_{CC} = 0 \text{ or } 3.6 \text{V}; \text{ V}_{I} = 5.5 \text{V}$			10	μA	
ц	input leakage current	$V_{CC} = 3.6V; V_I = V_{CC} \text{ or GND}$			±1	μΛ	
I _{OFF}	Output off current	$V_{CC} = 0V; V_{I} \text{ or } V_{O} = 0 \text{ to } 4.5V$			±100	μA	
I _{CC}	Quiescent supply current	V_{CC} = 3.6V; Outputs High, V_{I} = GND or V_{CC} , I_{O} = 0		0.5	1	mA	
ΔI_{CC}	Additional supply current per input pin ²	V_{CC} = 3V to 3.6V; One input at V _{CC} -0.6V, Other inputs at V _{CC} or GND			0.2	μA	
Cl	Input capacitance	$V_I = 3V \text{ or } 0$		3		pF	

NOTES:

1. All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^{\circ}C$. 2. This is the increase in supply current for each input at the specificed voltage level other than V_{CC} or GND.

AC CHARACTERISTICS

GND = 0V; $t_R = t_F = 2.5ns$; $C_L = 50pF$, $R_L = 500\Omega$; $T_{amb} = -40^{\circ}C$ to +85°C.

				LI	MITS		
SYMBOL PARAMETER		WAVEFORM	Vcc	$_{ m c}$ = 3.3V \pm 0	0.3V V _{CC} = 2.7V		UNIT
			MIN	TYP ¹	MAX	MAX	
f _{MAX}	Maximum clock frequency	1	150	345			MHz
t _{PLH} t _{PHL}	Propagation delay CPn to Qn or Qn	1	1.0 1.0	3.1 3.6	4.8 5.0	5.8 5.0	ns
t _{PLH} t _{PHL}	Propagation delay SDn, RDn to Qn or Qn	2	1.0 1.0	3.1 3.0	5.0 4.4	6.2 4.8	ns

NOTE:

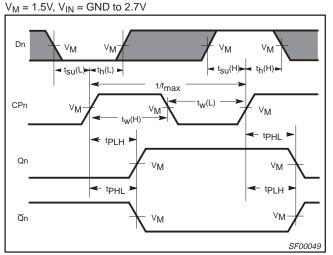
1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

AC SETUP REQUIREMENTS

				LIMITS		
SYMBOL	PARAMETER	WAVEFORM	V _{CC} = 3.3	$3V \pm 0.3V$	V _{CC} = 2.7V	UNIT
			MIN	TYP	MIN	
t _S (H) t _S (L)	Setup time Dn to CPn	1	1.7 1.4	0.6 0.4	1.8 1.6	ns
t _h (H) t _h (L)	Holdtime Dn to CPn	1	0.3 0	-0.3 -0.6	0.3 0	ns
t _W (H) t _W (L)	CPn Pulse Width	1	2.0 2.0	1.0 1.2	3.0 3.0	115
t _W (L)	SDn, RDn Pulse Width	2	2.0	1.0	3.0	
t _{rec}	Recovery time SDn, RDn tp CPn	3	0.5	-0.3	0.5	ns

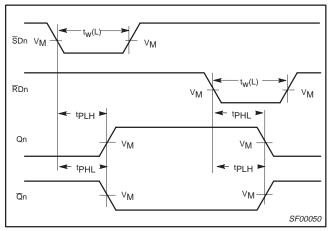
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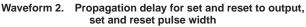
AC WAVEFORMS

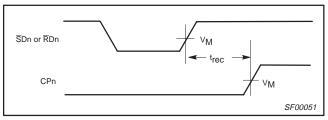


Waveform 1. Propagation delay for data to output, data setup time and hold times, and clock width, and maximum clock frequency

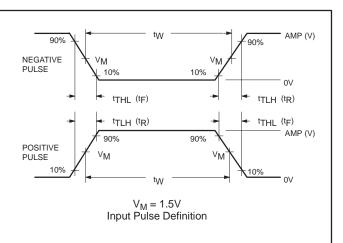
TEST CIRCUIT AND WAVEFORMS







Waveform 3. Recovery time for set or reset to clock



DEFINITIONS

- R_L = Load resistor; see AC CHARACTERISTICS for value.
- C_L = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.
- $\label{eq:RT} \textbf{R}_{T} = \quad \mbox{Termination resistance should be equal to } \textbf{Z}_{OUT} \mbox{ of } \\ \mbox{pulse generators.} \end{cases}$

	INPUT PULSE REQUIREMENTS						
FAMILY	Amplitude	Rep. Rate	tw	t _R	t _F		
74LVT	2.7V	≤10MHz	500ns	≤2.5ns	≤2.5ns		

SV00022

OUTLINE

VERSION

SOT108-1

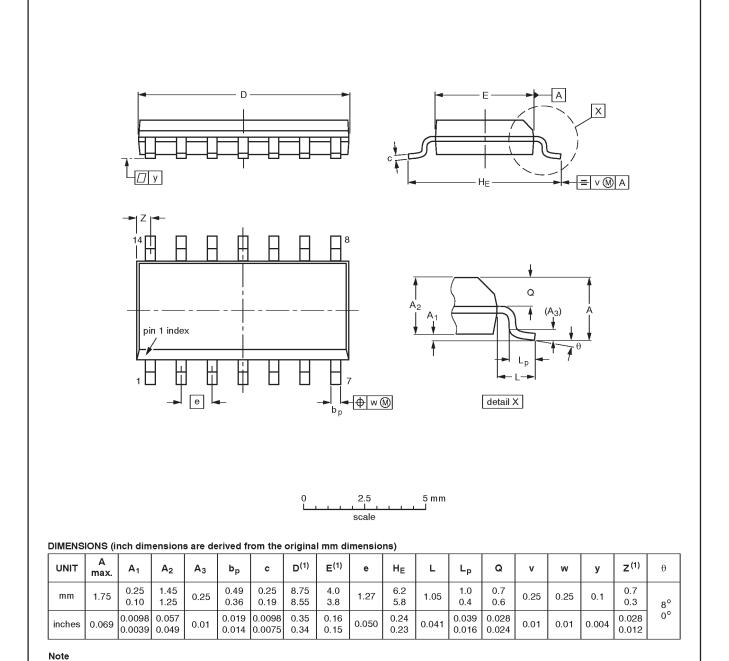
3.3V Dual D-type flip-flop



1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

IEC

076E06\$



Product specification

74LVT74

SOT108-1

EIAJ

EUROPEAN

PROJECTION

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ISSUE DATE

91-08-13

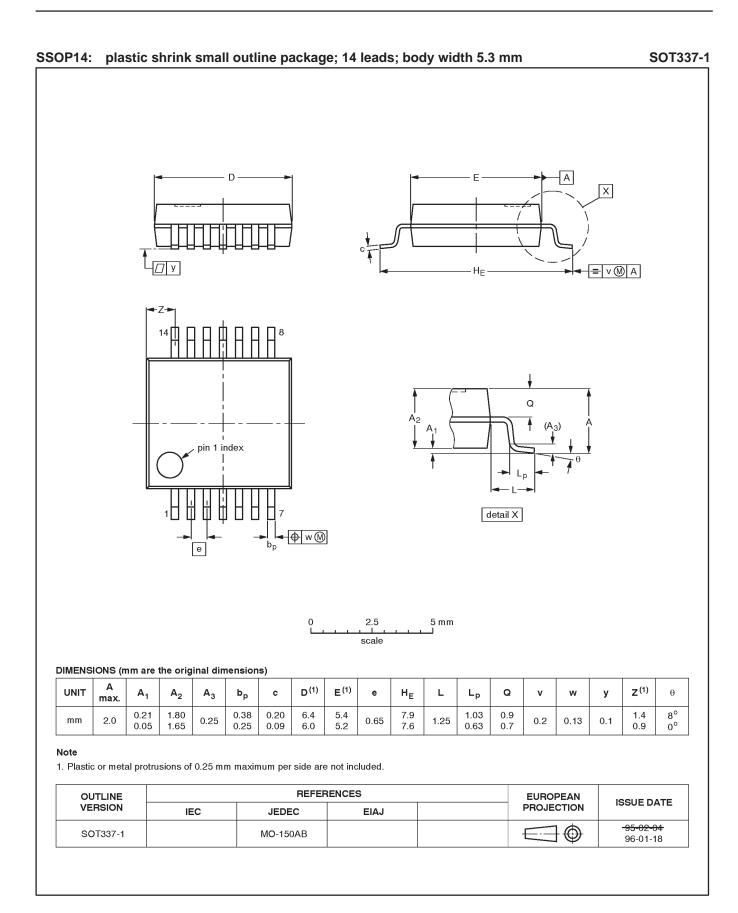
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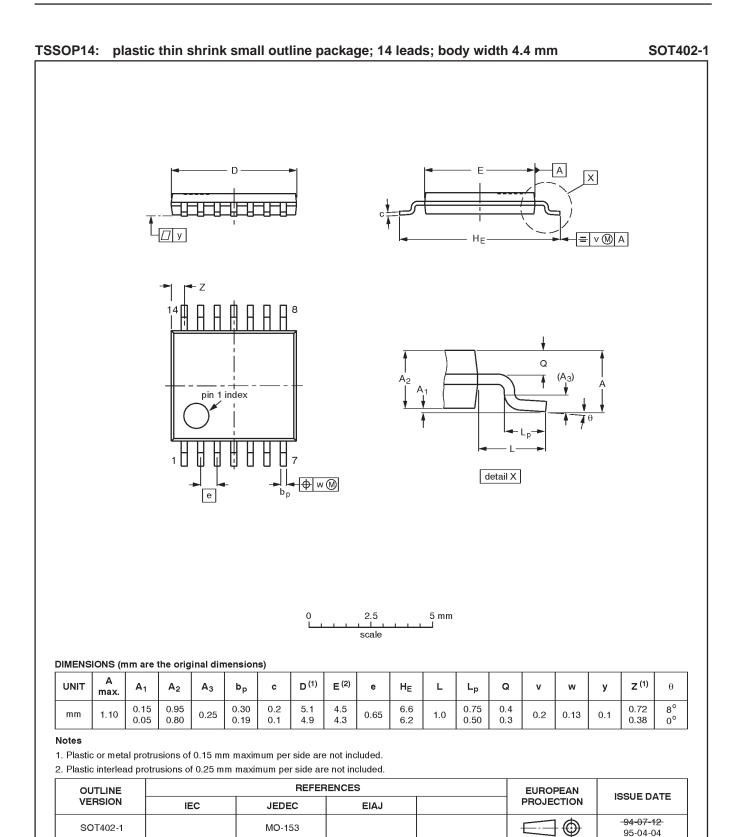
MS-012AB

74LVT74



1996 Aug 28

74LVT74



74LVT74

NOTES

74LVT74

DEFINITIONS				
Data Sheet Identification Product Status Definition		Definition		
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.		
Preliminary Specification	Preliminary Specification Preproduction Product This data sheet contains preliminary data, and supplementary data will be published. Semiconductors reserves the right to make changes at any time without notice in ore and supply the best possible product. and supply the best possible product.			
Product Specification	Full Production	This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.		

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